



A Product Line of Diodes Incorporated

# DMN2300UFL4

#### 20V DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	Max R <sub>DS(on)</sub>	I <sub>D</sub> max T <sub>A</sub> = 25°C (Notes 6)
20V	195mΩ @ $V_{GS}$ = 4.5V	2.11A
	260mΩ @ V <sub>GS</sub> = 2.5V	1.83A
	380mΩ @ V <sub>GS</sub> = 1.8V	1.51A
	520mΩ @ $V_{GS}$ = 1.5V	1.29A

## **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

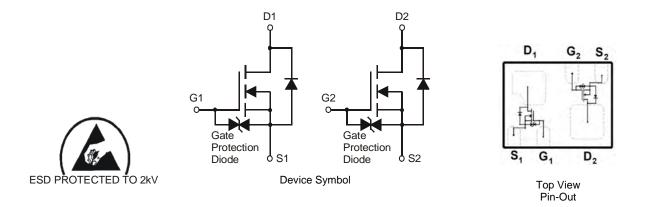
Load switch

#### **Features and Benefits**

- Footprint of just 1.3 mm<sup>2</sup>
- Ultra Low Profile Package 0.4mm profile
- On resistance <200mΩ
- Low Gate Threshold Voltage
- Fast Switching Speed
- Ultra-Small Surface Mount Package
- ESD Protected Gate 2KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: X2-DFN1310-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @



#### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN2300UFL4-7	23N	7	8	3000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**

23N

23N = Product Type Marking Code





## DMN2300UFL4

#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

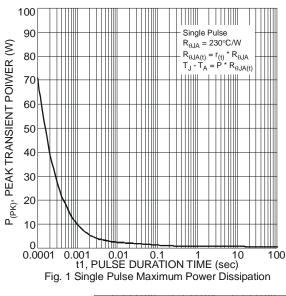
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±8	V
Continuous Drain Current (Note 6)	Steady State	T <sub>A</sub> = 25°C T <sub>A</sub> = 85°C	ID	2.11 1.19	A
Pulsed Drain Current (Note 7)			I <sub>DM</sub>	6.0	A

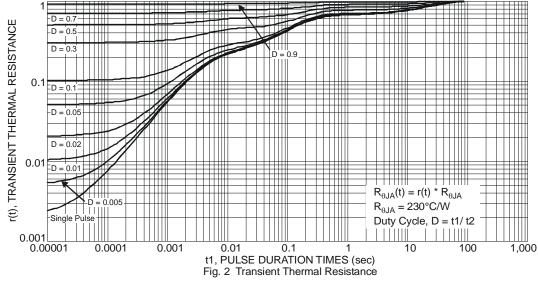
## Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	Р	0.53	W	
	(Note 6)	P <sub>D</sub>	1.39	vv	
Thermal Desistance, Junction to Ambient	(Note 5)	D	238	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	90	°C/w	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout;

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate
Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.







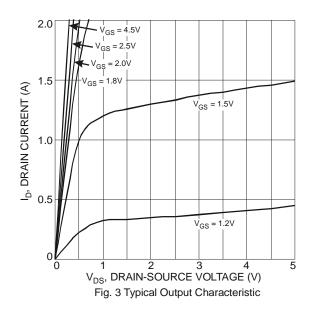
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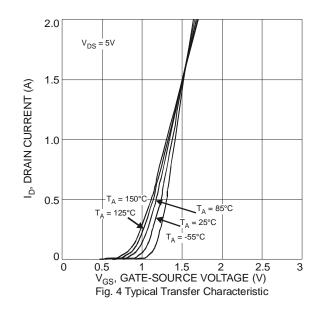
ZETEX

## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	-	-	V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = 25°C	I <sub>DSS</sub>	-	-	1	μΑ	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	10	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.45	-	0.95	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
		-	-	195		$V_{GS} = 4.5V, I_D = 300mA$	
Static Drain-Source On-Resistance	Б	-	-	260		$V_{GS} = 2.5V, I_D = 250mA$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>			380	mΩ	$V_{GS} = 1.8V, I_{D} = 100mA$	
		-	-	520		$V_{GS} = 1.5V, I_D = 50mA$	
Forward Transfer Admittance	Y <sub>fs</sub>	40	-	-	mS	$V_{DS} = 3V, I_{D} = 30mA$	
Diode Forward Voltage	V <sub>SD</sub>	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 300mA$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C <sub>iss</sub>	-	64.3	-	pF		
Output Capacitance	Coss	-	6.1	-	pF	$V_{DS} = 25V, V_{GS} = 0V,$ = f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	4.5	-	pF		
Gate Resistance	Rg	-	70	-	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	-	1.6	-	nC		
Gate-Source Charge	Q <sub>gs</sub>	-	0.2	-	nC	$V_{GS} = 4.5V, V_{DS} = 15V,$	
Gate-Drain Charge	Q <sub>gd</sub>	-	0.2	-	nC	$I_D = 1A$	
Turn-On Delay Time	t <sub>D(on)</sub>	-	3.5	-	ns		
Turn-On Rise Time	tr	-	2.8	-	ns	$V_{DS} = 10V, I_D = 1A$	
Turn-Off Delay Time	t <sub>D(off)</sub>	-	38	-	ns	$V_{GS} = 10V, R_{G} = 6\Omega$	
Turn-Off Fall Time	t <sub>f</sub>	-	13	-	ns	7	

Notes: 8. Short duration pulse test used to minimize self-heating effect.

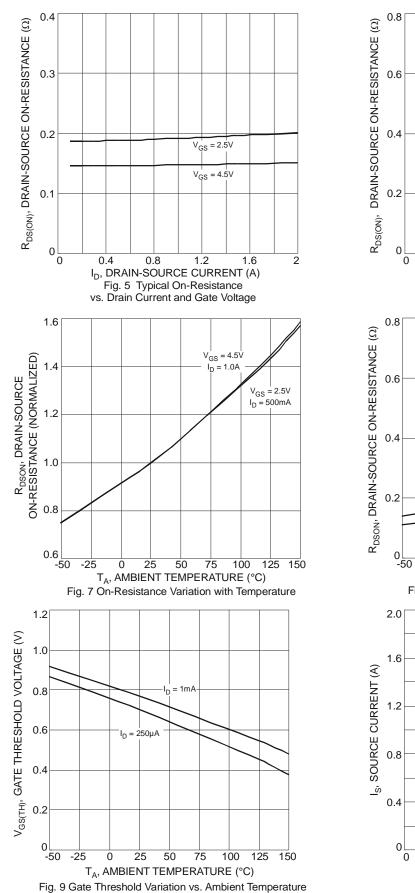






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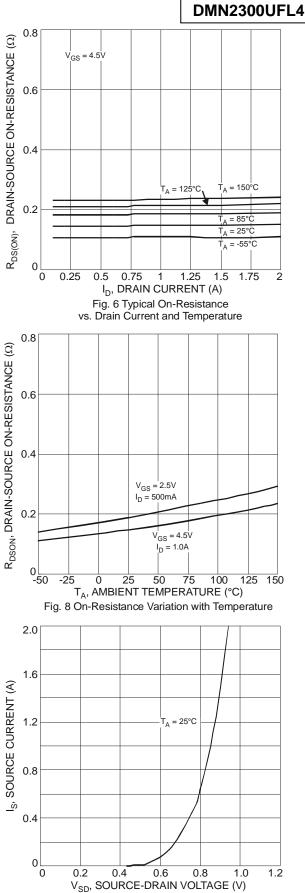


Fig. 10 Diode Forward Voltage vs. Current

DMN2300UFL4

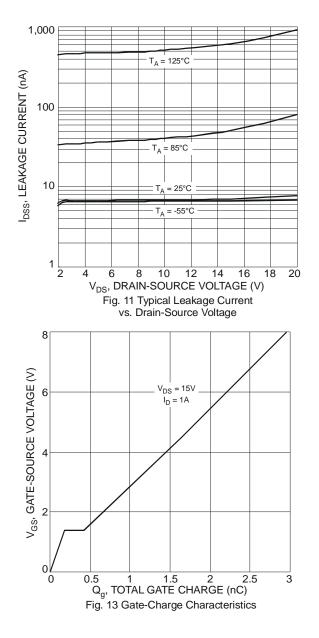
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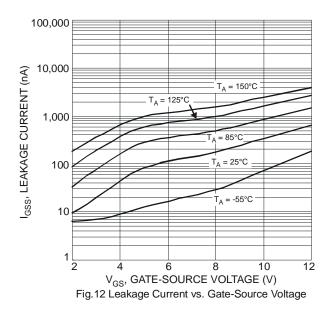


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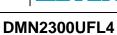




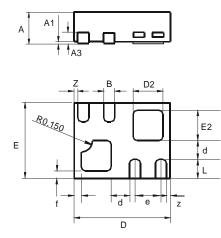






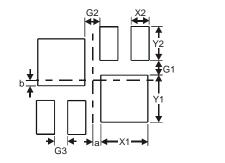


## **Package Outline Dimensions**



	X2-DFN1310-6					
Dim	Min	Max	Тур			
Α		0.40				
A1	0	0.05	0.02			
A3			0.13			
b	0.10	0.20	0.15			
D	1.25	1.38	1.30			
d			0.25			
D2	0.30	0.50	0.40			
Е	0.95	1.075	1.00			
е	_		0.35			
E2	0.30	0.50	0.40			
f		_	0.10			
L	0.20	0.30	0.25			
Z		_	0.05			
All D	All Dimensions in mm					

## **Suggested Pad Layout**



Dimensions	Value (in mm)
G1	0.16
G2	0.17
G3	0.15
X1	0.52
X2	0.20
Y1	0.52
Y2	0.375
а	0.09
b	0.06



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